

# Octal D-Type Flip-Flop with 3-State Output

# MC74VHC574, MC74VHCT574A

The MC74VHC574/MC74VHCT574A is an advanced high speed CMOS octal flip-flop with 3-state output fabricated with silicon gate CMOS technology. The device achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input and an output enable input. When the output enable input is high, the eight outputs are in a high impedance state.

The MC74VHC574 inputs are compatible with standard CMOS levels while the MC74VHCT574A inputs are compatible with TTL levels. The MC74VHCT574A can be used as a level converter for interfacing 3.3 V to 5.0 V, because it has full 5.0 V CMOS level output swings.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The MC74VHC574 and MC74VHCT574A input structures tolerate voltages up to 5.5 V, allowing the interface of 5 V systems to 3 V systems.

The MC74VHCT574A output structures provide protection when  $V_{CC}$  = 0 V. These output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

#### **Features**

- High Speed:  $f_{max} = 180 \text{ MHz (Typ)}$  at  $V_{CC} = 5.0 \text{ V}$
- $f_{max}$  = 140 MHz (Typ) at  $V_{CC}$  = 5.0 V • Low Power Dissipation:  $I_{CC}$  = 4.0  $\mu$ A (Max) at  $T_A$  = 25°C
- High Noise Immunity:  $V_{NIH} = V_{NIL} = 28\%$
- Power Down Protection Provided
- Balanced Propagation Delays
- Designed for: 2.0 V to 5.5 V (VHC)

4.5 V to 5.5 V (VHCT)

• Low Noise:  $V_{OLP} = 1.2 \text{ V (Max) (VHC)}$ 

 $V_{OLP} = 1.6 \text{ V (Max) (VHCT)}$ 

- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 100 mA
- ESD Performance: Human Body Model > 2000 V;
- Chip Complexity: 286 FETs or 71.5 Equivalent Gates
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

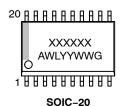


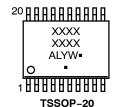
SOIC-20 DW SUFFIX CASE 751D



TSSOP-20 DT SUFFIX CASE 948E

#### **MARKING DIAGRAMS**





A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

#### **PIN ASSIGNMENT**

			•
OE [	1●	20	] v <sub>cc</sub>
D0 [	2	19	] Q0
D1 [	3	18	] Q1
D2 [	4	17	] Q2
D3 [	5	16	] Q3
D4 [	6	15	] Q4
D5 [	7	14	] Q5
D6 [	8	13	] Q6
D7 [	9	12	] Q7
GND [	10	11	] CP
,			

#### **FUNCTION TABLE**

	INPUTS	OUTPUT	
OE	СР	Q	
L L H	, , , , , , , , , , , , , , , , , , ,	H L X	H L No Change Z

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 10 of this data sheet.

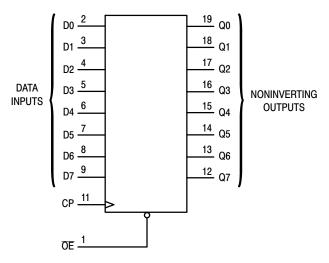


Figure 1. Logic Diagram

#### **MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage (MC74VHC)		-0.5 to V <sub>CC</sub> + 0.5	V
	DC Output Voltage (MC74VHCT)	Active Mode (High or Low State)  Tristate Mode (Note 1)  Power-Off Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	
I <sub>IN</sub>	DC Input Current, per Pin		±20	mA
l <sub>out</sub>	DC Output Current, Per Pin		±25	mA
I <sub>CC</sub>	DC Supply Current, V <sub>CC</sub> and GND Pins		±75	mA
I <sub>IK</sub>	Input Clamp Current		-20	mA
I <sub>OK</sub>	Output Clamp Current	MC74VHC574 MC74VHCT574A	±20 –20	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$ heta_{JA}$	Thermal Resistance (Note 2)	SOIC-20W TSSOP-20	96 150	°C/W
P <sub>D</sub>	Power Dissipation in Still Air at 25°C	SOIC-20W TSSOP-20	1302 833	mW
MSL	Moisture Sensitivity	SOIC-20W All Other Packages	Level 3 Level 1	_
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.574 in	_
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 N/A	٧
I <sub>LATCHUP</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- 2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
- 3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.
  4. Tested to EIA/JESD78 Class II.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
MC74VHC					•
V <sub>CC</sub>	DC Supply Voltage		2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage (Note 5)		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (Note 5)		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Rate	V <sub>CC</sub> = 3.0 V to 3.6 V V <sub>CC</sub> = 4.5 V to 5.5 V	0 0	100 20	ns/V
MC74VHC	т				•
V <sub>CC</sub>	DC Supply Voltage		4.5	5.5	V
V <sub>IN</sub>	DC Input Voltage (Note 5)		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (Note 5) A	ctive Mode (High or Low State)  Tristate Mode  Power-Off Mode ( $V_{CC} = 0 V$ )	0 0 0	V <sub>CC</sub> 5.5 5.5	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Rate	V <sub>CC</sub> = 4.5 V to 5.5 V	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC ELECTRICAL CHARACTERISTICS (MC74VHC574)

			V <sub>CC</sub>		T <sub>A</sub> = 25°C	;	T <sub>A</sub> = - 40	0 to 85°C	
Symbol	Parameter	Test Conditions	V	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage		2.0 3.0 to 5.5	1.50 V <sub>CC</sub> x 0.7			1.50 V <sub>CC</sub> x 0.7		V
V <sub>IL</sub>	Maximum Low-Level Input Voltage		2.0 3.0 to 5.5			0.50 V <sub>CC</sub> x 0.3		0.50 V <sub>CC</sub> x 0.3	V
V <sub>OH</sub>	Minimum High-Level Output Voltage	$V_{in} = V_{IH}$ or $V_{IL}$ $I_{OH} = -50 \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		
V <sub>OL</sub>	Maximum Low-Level Output Voltage	$V_{in} = V_{IH}$ or $V_{IL}$ $I_{OL} = 50 \mu A$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{in} = V_{IH}$ or $V_{IL}$ $I_{OL} = 4$ mA $I_{OL} = 8$ mA	3.0 4.5			0.36 0.36		0.44 0.44	
l <sub>in</sub>	Maximum Input Leak- age Current	V <sub>in</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
I <sub>OZ</sub>	Maximum Three- State Leakage Cur- rent	$V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$	5.5			±0.25		±2.5	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>in</sub> = V <sub>CC</sub> or GND	5.5			4.0		40.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

<sup>5.</sup> Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

#### AC ELECTRICAL CHARACTERISTICS (MC74VHC574)

					T <sub>A</sub> = 25°C		T <sub>A</sub> = - 40	) to 85°C	
Symbol	Parameter	Test Condi	tions	Min	Тур	Max	Min	Max	Unit
f <sub>max</sub>	Maximum Clock Frequency (50% Duty Cycle)	$V_{CC} = 3.3 \pm 0.3 \text{ V}$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	80 50	125 75	- -	65 45	- -	ns
		$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	130 85	180 115	- -	110 75	- -	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, CP to Q	$V_{CC} = 3.3 \pm 0.3$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	-	8.5 11.0	13.2 16.7	1.0 1.0	15.5 19.0	ns
		$V_{CC} = 5.0 \pm 0.5 V$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	-	5.6 7.1	8.6 10.6	1.0 1.0	10.0 12.0	
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time, OE to Q	$V_{CC} = 3.3 \pm 0.3 V$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50pF	- -	8.2 10.7	12.8 16.3	1.0 1.0	15.0 18.5	ns
		$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 15pF C <sub>L</sub> = 50 pF	- -	5.9 7.4	9.0 11.0	1.0 1.0	10.5 12.5	
t <sub>PLZ</sub> ,	Output Disable Time,	$V_{CC} = 3.3 \pm 0.3 \text{ V}$	C <sub>L</sub> = 50 pF	-	11.0	15.0	1.0	17.0	ns
t <sub>PHZ</sub>	OE to Q	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 50 pF	-	7.1	10.1	1.0	11.5	
t <sub>OSLH</sub> , t <sub>OSHL</sub>	Output to Output Skew	V <sub>CC</sub> = 3.3 ± 0.3 V (Note 6)	C <sub>L</sub> = 50 pF	-	-	1.5	_	1.5	ns
		V <sub>CC</sub> = 5.0 ± 0.5 V (Note 6)	C <sub>L</sub> = 50 pF	-	-	1.0	_	1.0	ns
C <sub>in</sub>	Maximum Input Capacitance			-	4	10	_	10	pF
C <sub>out</sub>	Maximum Three-State Output Capacitance, Output in High- Impedance State			-	6	-	-	-	pF

		Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
$C_{PD}$	Power Dissipation Capacitance (Note 7)	28	pF

<sup>6.</sup> Parameter guaranteed by design. t<sub>OSLH</sub> = |t<sub>PLHm</sub> − t<sub>PLHn</sub>|, t<sub>OSHL</sub> = |t<sub>PHLm</sub> − t<sub>PHLn</sub>|.

7. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>/8 (per flip-flop). C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

## NOISE CHARACTERISTICS (MC74VHC574) ( $C_L = 50 \text{ pF}, V_{CC} = 5.0 \text{ V}$ )

		T <sub>A</sub> = 25°C		
Symbol	Parameter	Тур	Max	Unit
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	0.9	1.2	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	-0.9	-1.2	V
$V_{IHD}$	Minimum High Level Dynamic Input Voltage	-	3.5	V
$V_{ILD}$	Maximum Low Level Dynamic Input Voltage	-	1.5	V

## TIMING REQUIREMENTS (MC74VHC574)

			T <sub>A</sub> = 25°C		T <sub>A</sub> = - 40 to 85°C	
Symbol	Parameter	Test Conditions	Тур	Limit	Limit	Unit
t <sub>su</sub>	Minimum Setup Time, D to CP	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \pm 0.5 \text{ V}$	-	3.5 3.5	3.5 3.5	ns
t <sub>h</sub>	Minimum Hold Time, CP to D	$V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \pm 0.5 \text{ V}$	- -	1.5 1.5	1.5 1.5	ns
t <sub>w</sub>	Minimum Pulse Width, CP	$V_{CC} = 3.3 \pm 0.3 \text{ V} $ $V_{CC} = 5.0 \pm 0.5 \text{ V}$	- -	5.0 5.0	5.5 5.0	ns

#### DC ELECTRICAL CHARACTERISTICS (MC74VHCT574A)

			V <sub>CC</sub>	•	T <sub>A</sub> = 25	°C	T <sub>A</sub> = - 40	0 to 85°C	
Symbol	Parameter	Test Conditions	v	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	Minimum High-Level Input Voltage		4.5 to 5.5	2.0			2.0		V
$V_{IL}$	Maximum Low-Level Input Voltage		4.5 to 5.5			0.8		0.8	V
V <sub>OH</sub>		I <sub>OH</sub> = - 50 μA	4.5	4.4	4.5		4.4		V
		I <sub>OH</sub> = - 8 mA	4.5	3.94			3.80		
V <sub>OL</sub>	Maximum Low-Level Output	I <sub>OL</sub> = 50 μA	4.5		0.0	0.1		0.1	V
	Voltage $V_{in} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 8 mA	4.5			0.36		0.44	
I <sub>in</sub>	Maximum Input Leakage Current	V <sub>in</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ
l <sub>OZ</sub>	Maximum 3-State Leakage Current	$V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$	5.5			±0.25		±2.5	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>in</sub> = V <sub>CC</sub> or GND	5.5			4.0		40.0	μΑ
I <sub>CCT</sub>	Quiescent Supply Current	Per Input: V <sub>IN</sub> = 3.4 V Other Input: V <sub>CC</sub> or GND	5.5			1.35		1.50	mA
I <sub>OPD</sub>	Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			0.5		5.0	μΑ

#### AC ELECTRICAL CHARACTERISTICS (MC74VHCT574A)

				T <sub>A</sub> = 25°C		°C	T <sub>A</sub> = - 40 to 85°C		
Symbol	Parameter	Test Condi	Test Conditions		Тур	Max	Min	Max	Unit
f <sub>max</sub>	Maximum Clock Frequency (50% Duty Cycle)	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF	90 85	140 130		80 95		MHz
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, CP to Q	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		4.1 5.6	9.4 10.4	1.0 1.0	10.5 11.5	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time, OE to Q	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 15 pF C <sub>L</sub> = 50 pF		6.5 7.3	10.2 11.2	1.0 1.0	11.5 12.5	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Output Disable Time, OE to Q	$V_{CC} = 5.0 \pm 0.5 \text{ V}$	C <sub>L</sub> = 50 pF		7.0	11.2	1.0	12.0	ns
t <sub>OSLH</sub> , t <sub>OSHL</sub>	Output to Output Skew	V <sub>CC</sub> = 5.0 ± 0.5 V (Note 8)	C <sub>L</sub> = 50 pF			1.0		1.0	ns
C <sub>in</sub>	Maximum Input Capacitance				4	10		10	pF
C <sub>out</sub>	Maximum Three-State Output Capacitance, Output in High-Impedance State				9				pF

		Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
$C_{PD}$	Power Dissipation Capacitance (Note 9)	25	pF

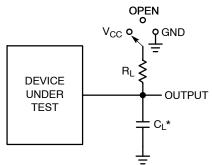
Parameter guaranteed by design. t<sub>OSLH</sub> = |t<sub>PLHm</sub> - t<sub>PLHn</sub>|, t<sub>OSHL</sub> = |t<sub>PHLm</sub> - t<sub>PHLn</sub>|.
 C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>/8 (per flip-flop). C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

## NOISE CHARACTERISTICS (MC74VHCT574A) ( $C_L = 50 \text{ pF}, V_{CC} = 5.0 \text{ V}$ )

		T <sub>A</sub> = 25°C		
Symbol	Parameter	Тур	Max	Unit
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	1.2	1.6	٧
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>		-1.6	V
V <sub>IHD</sub>	Minimum High Level Dynamic Input Voltage		2.0	V
$V_{ILD}$	Maximum Low Level Dynamic Input Voltage		0.8	V

## TIMING REQUIREMENTS (MC74VHCT574A)

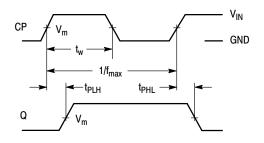
			T <sub>A</sub> = 25°C		T <sub>A</sub> = - 40 to 85°C	
Symbol	Parameter	Test Conditions	Тур	Limit	Limit	Unit
t <sub>su</sub>	Minimum Setup Time, D to CP	$V_{CC} = 5.0 \pm 0.5 \text{ V}$		6.5	8.5	ns
t <sub>h</sub>	Minimum Hold Time, CP to D	$V_{CC} = 5.0 \pm 0.5 \text{ V}$		2.5	2.5	ns
t <sub>w</sub>	Minimum Pulse Width, CP	$V_{CC} = 5.0 \pm 0.5 \text{ V}$		2.5	2.5	ns



*C <sub>L</sub> Includes probe and jig capacitance	е
Input signal $t_p = t_p = 3$ ns	

Test	Switch Position	CL	$R_{L}$
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics	1 kΩ
t <sub>PLZ</sub> / t <sub>PZL</sub>	V <sub>CC</sub>	Table	
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND		

Figure 2. Test Circuits



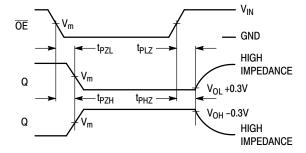


Figure 3. Switching Waveforms

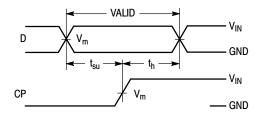


Figure 4.

Device	$V_{IN}, V$	V <sub>m</sub> , V
MC74VHC574	V <sub>CC</sub>	50% x V <sub>CC</sub>
MC74VHCT574A	3 V	1.5 V

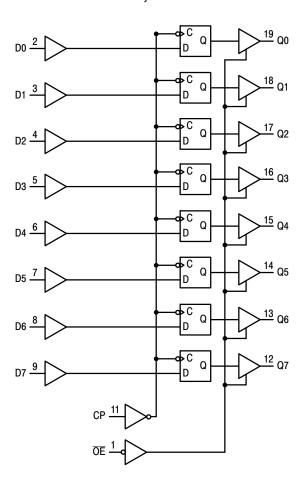


Figure 5. Expanded Logic Diagram

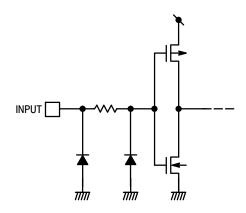


Figure 6. Input Equivalent Circuit

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
MC74VHC574DWG	VHC574G	SOIC-20W	38 Units / Rail
MC74VHC574DWR2G	VHC574G	SOIC-20W	1000 / Tape & Reel
MC74VHC574DTG	VHC 574	TSSOP-20	75 Units / Rail
MC74VHC574DTR2G	VHC 574	TSSOP-20	2500 / Tape & Reel
MC74VHCT574ADWR2G	VHCT574AG	SOIC-20W	1000 / Tape & Reel
MC74VHCT574ADTR2G	VHCT 574A	TSSOP-20	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

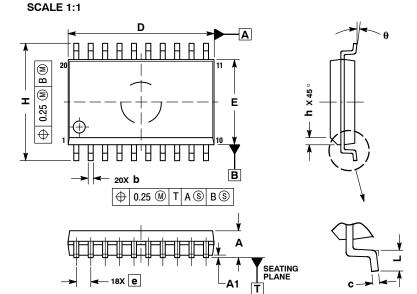
\*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable





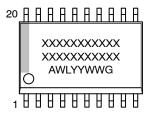
SOIC-20 WB CASE 751D-05 **ISSUE H** 

**DATE 22 APR 2015** 



- DIMENSIONS ARE IN MILLIMETERS.
   INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.35	2.65	
A1	0.10	0.25	
b	0.35	0.49	
С	0.23	0.32	
D	12.65	12.95	
E	7.40	7.60	
е	1.27 BSC		
Н	10.05	10.55	
h	0.25	0.75	
L	0.50	0.90	
A	0 °	7 °	



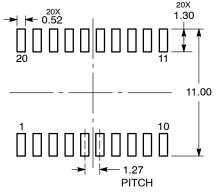
**GENERIC MARKING DIAGRAM\*** 

XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

#### **RECOMMENDED SOLDERING FOOTPRINT\***



DIMENSIONS: MILLIMETERS

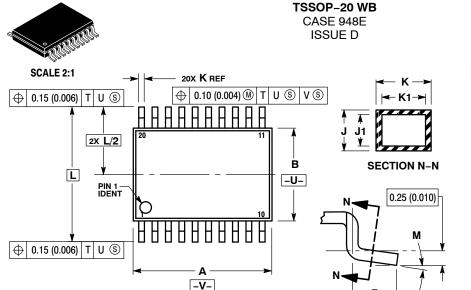
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DESCRIPTION:	SOIC-20 WB		PAGE 1 OF 1	

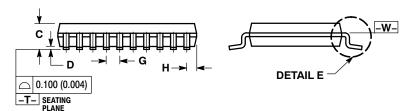
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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**DATE 17 FEB 2016** 







**DETAIL E** 

#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

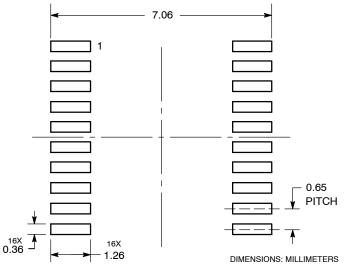
  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  4. DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
  INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
  DIMENSION K DOES NOT INCLUDE
- DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K
  DIMENSION AT MAXIMUM MATERIAL CONDITION.
  TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
  DIMENSION A AND B ARE TO BE
  DETERMINED AT DATUM PLANE -W-.

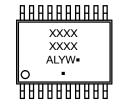
	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	6.40	6.60	0.252	0.260	
В	4.30	4.50	0.169	0.177	
С		1.20		0.047	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.65	BSC	0.026	0.026 BSC	
Н	0.27	0.37	0.011	0.015	
7	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40 BSC		0.252	BSC	
M	0°	8°	0°	8°	

#### **RECOMMENDED SOLDERING FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



= Assembly Location

= Wafer Lot

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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